

# Cascadable Silicon Bipolar MMIC Amplifier

# Technical Data

#### **MSA-0485**

### **Features**

- Cascadable 50  $\Omega$  Gain Block
- 3 dB Bandwidth: DC to 3.6 GHz
- 8.0 dB Typical Gain at 1.0 GHz
- 12.5 dBm Typical  $P_{1 dB}$  at 1.0 GHz
- Unconditionally Stable (k>1)
- Low Cost Plastic Package

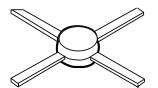
## **Description**

The MSA-0485 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost

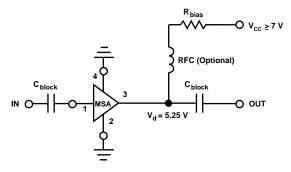
plastic package. This MMIC is designed for use as a general purpose  $50~\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using HP's  $10\,\mathrm{GHz}\,\mathrm{f_T}, 25\,\mathrm{GHz}\,\mathrm{f_{MAX}},$  silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

## 85 Plastic Package



## **Typical Biasing Configuration**



5965-9577E 6-338

MSA-0485 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>				
Device Current	85 mA				
Power Dissipation <sup>[2,3]</sup>	500 mW				
RF Input Power	+13dBm				
Junction Temperature	150℃				
Storage Temperature	−65 to 150°C				

Thermal Resistance $[2,4]$ :	
$\theta_{\rm jc} = 90^{\circ} \text{C/W}$	

#### Notes:

- $1. \ \,$  Permanent damage may occur if any of these limits are exceeded.
- 2.  $T_{CASE} = 25$ °C.
- 3. Derate at 11.1 mW/°C for  $T_{\rm C} > 105$  °C.
- 4. See MEASUREMENTS section "Thermal Resistance" for more information.

# Electrical Specifications [1], $T_A = 25$ °C

Symbol	<b>Parameters and Test Conditions:</b>	Units	Min.	Тур.	Max.	
GP	Power Gain ( $ S_{21} ^2$ )	f = 0.1 GHz			8.3	
		$f = 1.0 \mathrm{GHz}$		7.0	8.0	
$\Delta G_{ m P}$	Gain Flatness	f = 0.1  to  2.5  GHz	dB		± 0.7	
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		3.6	
VSWR	Input VSWR	f = 0.1  to  2.5  GHz			1.6:1	
vown	Output VSWR	f = 0.1  to  2.5  GHz			2.0:1	
NF	$50\Omega$ Noise Figure	f = 1.0  GHz	dB		7.0	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		12.5	
IP <sub>3</sub>	Third Order Intercept Point	f = 1.0  GHz	dBm		25.5	
$t_{\mathrm{D}}$	Group Delay	f = 1.0  GHz	psec		125	
$V_{d}$	Device Voltage		V	4.2	5.25	6.3
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

#### Note:

<sup>1.</sup> The recommended operating current range for this device is 30 to 70 mA. Typical performance as a function of current is on the following page.

MSA-0485 Typical Scattering Parameters (Z  $_{O}$  = 50  $\Omega,$   $T_{A}$  = 25  $^{\circ}C,$   $I_{d}$  = 50 mA)

Freq.	S <sub>11</sub>		$\mathbf{S}_{21}$		$\mathbf{S}_{12}$			$\mathbf{S}_{22}$		
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.21	177	8.4	2.63	175	-16.1	.156	2	.08	-16
0.2	.20	176	8.3	2.60	171	-16.2	.155	2	.08	-30
0.4	.20	172	8.2	2.57	163	-16.1	.156	3	.10	<b>-</b> 54
0.6	.19	171	8.1	2.55	155	-16.2	.155	5	.13	<b>-7</b> 1
0.8	.19	168	8.1	2.54	146	-16.0	.158	6	.16	<b>-</b> 83
1.0	.18	166	8.0	2.52	138	-15.7	.164	9	.18	<b>-9</b> 3
1.5	.16	167	7.8	2.46	117	-15.3	.171	11	.25	-116
2.0	.18	168	7.4	2.34	97	-14.6	.187	12	.29	-136
2.5	.21	173	6.9	2.21	83	-13.8	.204	16	.34	-150
3.0	.27	169	6.3	2.07	65	-13.4	.213	13	.38	-161
3.5	.33	161	5.7	1.92	48	-12.6	.234	9	.39	-172
4.0	.38	154	4.8	1.74	33	-12.3	.242	6	.37	-179
4.5	.42	145	4.1	1.59	18	-12.1	.249	3	.36	-174
5.0	.44	131	3.3	1.46	4	-11.7	.259	<b>-</b> 3	.34	-165

A model for this device is available in the DEVICE MODELS section.

# Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

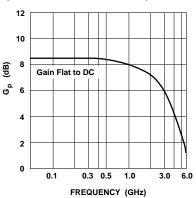


Figure 1. Typical Power Gain vs. Frequency,  $T_A$  = 25°C,  $I_d$  = 50 mA.

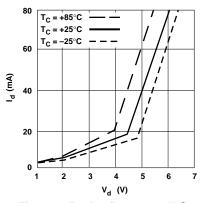


Figure 2. Device Current vs. Voltage.

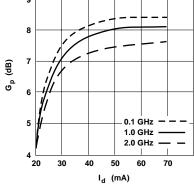


Figure 3. Power Gain vs. Current.

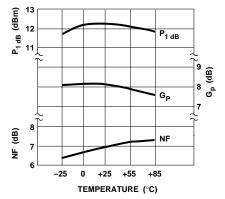


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature,  $f=1.0~\mathrm{GHz}$ ,  $I_d=50\mathrm{mA}$ .

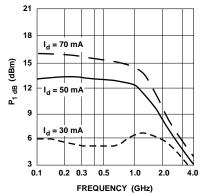


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

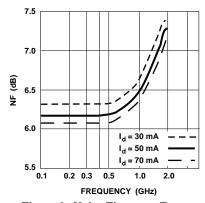


Figure 6. Noise Figure vs. Frequency.

# **85 Plastic Package Dimensions**

